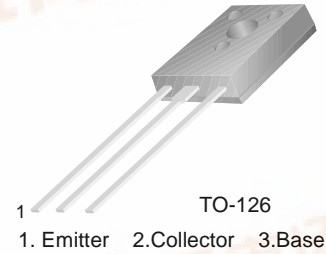


**FAIRCHILD**  
SEMICONDUCTOR®

## KSC5042M

### High Voltage Switching Dynamic Focus Application

- High Collector-Emitter Breakdown Voltage :  $V_{CE0}=900V$
- Small  $C_{ob} = 2.8pF$  (Typ.)
- Wide S.O.A
- High reliability



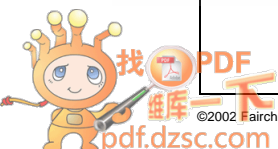
### NPN Triple Diffused Planar Silicon Transistor

#### Absolute Maximum Ratings $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	1500	V
$V_{CEO}$	Collector-Emitter Voltage	900	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current (DC)	100	mA
$I_{CP}$	Collector Current (Pulse)	300	mA
$P_C$	Collector Dissipation ( $T_C=25^\circ C$ )	4	W
$T_J$	Junction Temperature	150	$^\circ C$
$T_{STG}$	Storage Temperature	- 55 ~ 150	$^\circ C$

#### Electrical Characteristics $T_C=25^\circ C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$BV_{CBO}$	Collector-Base Breakdown Voltage	$I_C = 1mA, I_E = 0$	1500			V
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 5mA, I_B = 0$	900			V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E = 1mA, I_C = 0$	5			V
$I_{CBO}$	Collector Cut-off Current	$V_{CB} = 900V, I_E = 0$			10	$\mu A$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = 4V, I_C = 0$			10	$\mu A$
$h_{FE}$	DC Current Gain	$V_{CE} = 5V, I_C = 10mA$	30			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 20mA, I_B = 4mA$			5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 20mA, I_B = 4mA$			2	V
$C_{ob}$	Output Capacitance	$V_{CB} = 100V, f = 1MHz$		2.8		pF



# Typical Characteristics

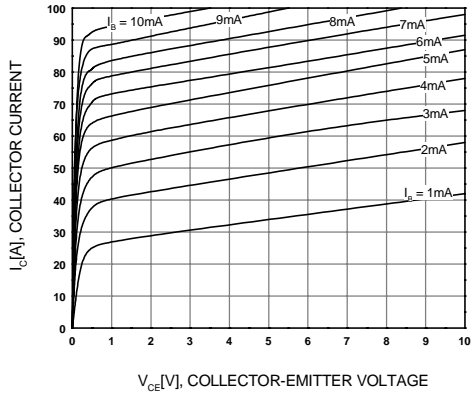


Figure 1. Static Characteristic

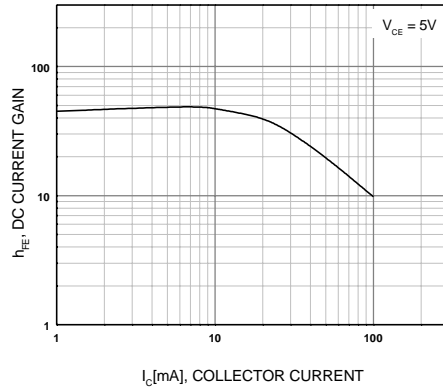


Figure 2. DC current Gain

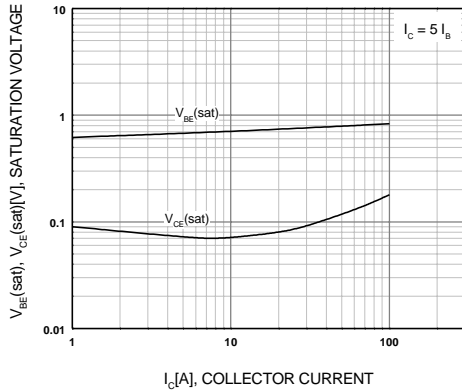


Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

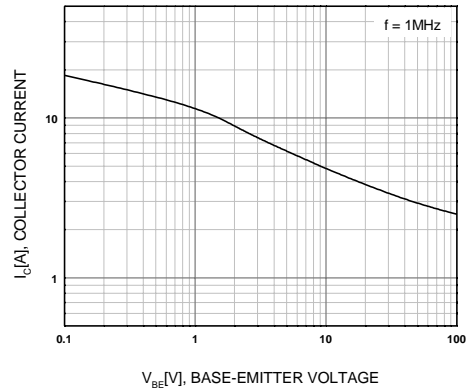


Figure 4. Collector-Base Capacitance

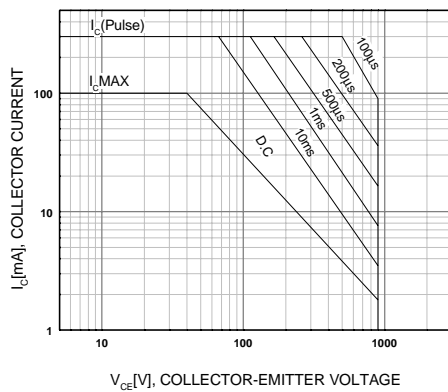


Figure 5. Safe Operating Area

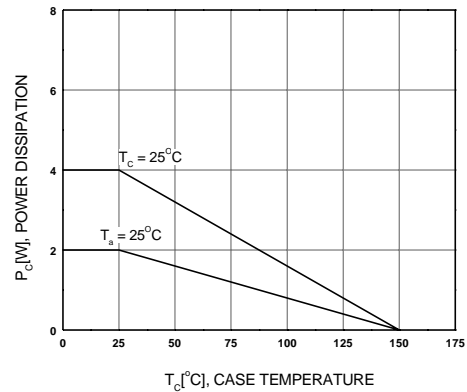
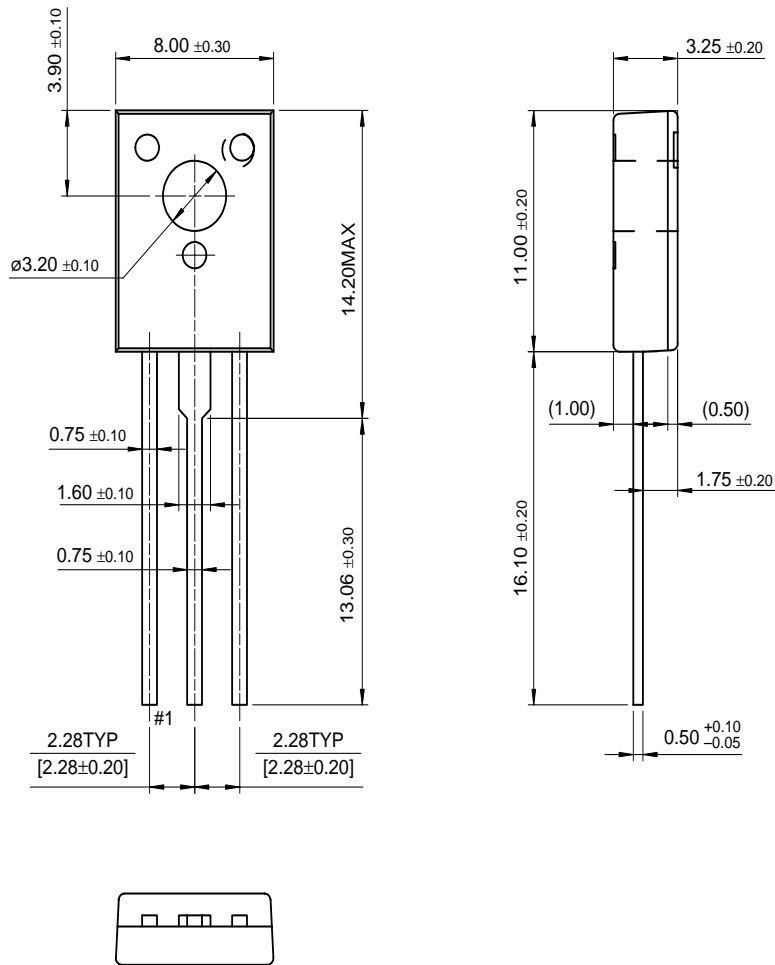


Figure 6. Power Derating

# Package Dimensions

## TO-126



Dimensions in Millimeters

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Bottomless™	FAST®	LittleFET™	Power247™	SuperSOT™-3
CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOMET™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E <sup>2</sup> CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I <sup>2</sup> C™	OCX™	RapidConfigure™	UHC™
Across the board. Around the world.™		OCXPro™	RapidConnect™	UltraFET®
The Power Franchise™		OPTOLOGIC®	SILENT SWITCHER®	VCX™
Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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